TOSHIBA CMOS Integrated Circuit Silicon Monolithic

# **TC94B06WBG**

### Stereo Headphone Amplifier with Electronic Volume

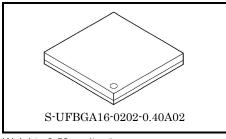
The TC94B06WBG is a G-class stereo headphone amplifier IC with electronic volume function.

It is built in a charge pump circuit, so output coupling capacitor isn't needed. And it is suitable for portable audio and mobile phone etc.

#### **Features**

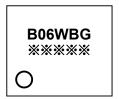
- It is high efficiency according to headphone circuit adoption of G-Class type.
- Differential inputs
- Capability to drive : RL=16 to 600 ohm
- SGND for Tuner application

  It prevents deterioration by channel separation when a headphone
  GND is used as FM tuner antennae.
- I2C Bus
- Volume control -59 to +4dB, 32 steps, Mute function
- Channel independent shutdown control and short-circuit protection
- High SNR (AVDD=3.6V, A-weighting) S/N=102dB (Typ.)
- Package WCSP 16pin , 0.4mm pitch
- Operating supply voltage range: Ta = 25°C
   AVDD (opr) = 2.3 to 4.8 V

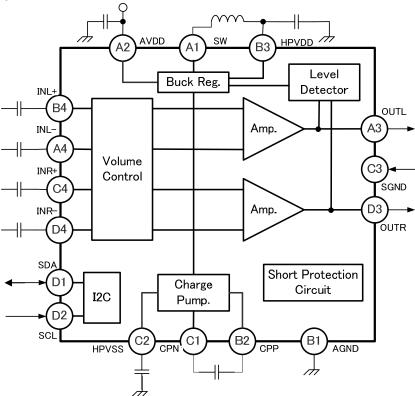


Weight: 3.53mg (typ.)

Marking:



## **Block Diagram**



Some of the functional blocks, circuits, or constants in the block diagram may be omitted or simplified for explanatory purpose.

## Pin Assignment (Top View)

(A)	ÁŽ	(Á¾	(A4)
SW	AVĎD	OÙTL	INL-
(B)	(B2)	(B3)	(B4)
AĞND	CPP	HPVDD	INL+
(C)	ĆŹ	ÇĞ	(C4)
CPN	HPVSS	SĞND	INR+
(DĴ)	(DŽ	(D3	(D4)
SDA	SCL	OÙTR	INR-



## **Pin Descriptions**

The equivalent circuit diagrams maybe simplified or some parts of them may be omitted for explanatory purpose.

Pin	No. and name	I/O	Function
A1	SW	-	Buck converter switching node
A2	AVDD	-	Power supply for the device; connected to battery
A3	OUTL	О	Left channel output
A4	INL-	I	Left channel input, negative terminal
B1	B1 AGND		Main GND
B2	B2 CPP		Charge pump flying capacitor, positive terminal
В3	B3 HPVDD		Power supply for headphone amplifier (DC/DC output)
B4	4 INL+		Left channel input, positive terminal
C1	CPN	_	Charge pump flying capacitor, negative terminal
C2	HPVSS	ı	Charge pump output
C3	SGND	_	GND sense; connect to headphone jack GND
C4	INR+	I	Right channel input, positive terminal
D1	SDA	I/O	I2C SDA line
D2	SCL	I	I2C SCL line
D3	OUTR	0	Right channel output
D4	INR-	I	Right channel input, negative terminal

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#### **Functional Description**

#### 1. I2C control

#### 1-1. Slave address

 $0xC0(Binary\ 11000000)$ : Writing mode  $0xC1(Binary\ 11000001)$ : Reading mode

#### 1-2. Register map

Register	D7	D6	D5	D4	D3	D2	D1	D0	Preset
0x01	HP_EN_L	HP_EN_R	0	0	0	0	Over current	SWS	0000 0001
0x02	Mute_L	Mute_R			Vo	lume		0	1100 0000
0x03	0	0	0	0	0	0	Hi-Z_L	Hi-Z_R	0000 0000

Table 1 Resister map

#### Note

The register address is for TOSHIBA testing from 0x04. Under no circumstances must any data be written to these registers. Writing to these bits may change the function of the device, or cause complete failure. If read, these bits may assume any value.

#### 0x01

Bit	Name	Value	Description
D7	HP EN L	0	Headphone amp. Lch disabled
Di	III _EN_L	1	Headphone amp. Lch enabled
D6	HP EN R	0	Headphone amp. Rch disabled
Ъб	IIF_EN_K	1	Headphone amp. Rch enabled
D1	Thermal	0	Protection circuit not activated (read only)
D1	Thermai	1	Protection circuit activated (read only)
D0	SWS	0	Device enabled (Charge pump circuit enabled)
DO	awa	1	Device disabled (Software shutdown)

Table 2 Resister explanation: 0x01

#### 0x02

Bit	Name	Value	Description
D7	Mute L	0	Headphone amp. Lch mute off
Di	Mute_L	1	Headphone amp. Lch mute on
D6	Muto D	0	Headphone amp. Rch mute off
Ъб	$\mathrm{Mute}_{-}\mathrm{R}$	1	Headphone amp. Rch mute on
D5:D1	Volume	_	These bits set the volume level
D9·D1	Volume	_	See volume table

Table 3 Resister explanation: 0x02

#### 0x03

Bit	Name	Value	Description
D1	Hi-Z L	0	Normal impedance of Lch output
D1	111 Z_L	1	High impedance of Lch output
D0	Hi-Z R	0	Normal impedance of Rch output
100	111 <sup>-</sup> Z_N	1	High impedance of Rch output

Table 4 Resister explanation: 0x03

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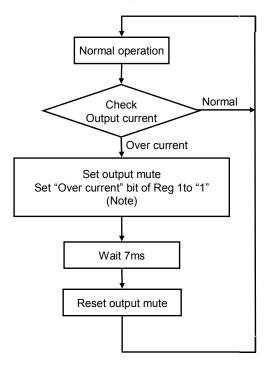
#### 1-3. Volume table

Gain control Mute[7:6], Volume[5:0]	Gain [dB]	Gain control Mute[7:6], Volume[5:0]	Gain [dB]
10xx xxxx	Mute_Lch	0001 111x	-13
01xx xxxx	Mute_Rch	0010 000x	-11
0000 000x	-59	0010 001x	-10
0000 001x	-55	0010 010x	-9
0000 010x	-51	0010 011x	-8
0000 011x	-47	0010 100x	-7
0000 100x	-43	0010 101x	-6
0000 101x	-39	0010 110x	-5
0000 110x	-35	0010 111x	-4
0000 111x	-31	0011 000x	-3
0001 000x	-27	0011 001x	-2
0001 001x	-25	0011 010x	-1
0001 010x	-23	0011 011x	0
0001 011x	-21	0011 100x	+1
0001 100x	-19	0011 101x	+2
0001 101x	-17	0011 110x	+3
0001 110x	-15	0011 111x	+4

#### 2. Over current protection circuit.

This IC built in the over current detection type of protection circuit.

The flow chart of the protection circuit is the following.



(Note) Over current bit is reset Reg 1 is read by I2C-bus.

Figure 1 : Flow of over current protection circuit

#### 3. I2C Timing Characteristics

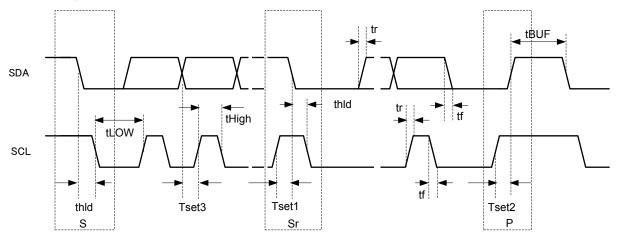


Figure 2: I2C timing

Characteristics	Symbol	Test Condition	Min.	Тур.	Max.	Unit
SCL Clock frequency	fSCL	_	_	_	400	kHz
Hold time, start condition to SCL	thld	_	0.6	_	_	$\mu$ s
Setup time, SCL to start condition	Tset1		0.6	_	_	$\mu$ s
Setup time, SCL to stop condition	Tset2	_	0.6	_	_	$\mu$ s
Data setup time	Tset3	_	100	_	_	ns
Bus free time between stop and start condition	tBUF	_	1.3	_	_	$\mu$ s
SCL clock width "Low"	tLOW	_	1.3	_	_	$\mu$ s
SCL clock width "High"	tHigh	_	0.6	_	_	$\mu$ s
SCL/SDA rise time	tr	_	_	_	300	ns
SCL/SDA fall time	tf	_	_	_	300	ns

#### 4. I2C BUS format

4-1. Write mode

This IC support the 3 formats.

Write mode 1
--------------

	D7	D6	D5	D4	D3	D2	D1	D0		D7 D6 D5 D4 D3 D2 D1 D0					D7 D6 D5 D4 D3 D2 D1 D0						D0	4			
S		Slave Address 0				Α		Re	egis	ter a	add	ress	s n		Α			of		ata jiste	er n			Α	Р

Write mode 2

:	S Slave Address 0 A	D7 D6 D5 D4 D3 D2 D1 D0  Register address n	A	D7 D6 D5 D4 D3 D2 D1 D0  Data  of Register n	Α	D7 D6 D5 D4 D3 D2 D1 D0  Register address m	A	D7 D6 D5 D4 D3 D2 D1 D0  Data  of Register m	Α	
		D7 D6 D5 D4 D3 D2 D1 D0  Register address x	Α	D7 D6 D5 D4 D3 D2 D1 D0  Data  of Register x	Α	Р				

Write mode 3



Data A P of Register x

S: Start condition, A: Acknowledge, P: Stop condition

Figure 3: Format of write mode

# 4-2. Read mode

TOSHIBA

This IC support the following format.

	D7 D6 D5 D4 D3 D2 D1	D0		D7 D6 D5 D4 D3 D2 D1 D0		D7 D6 D5 D4 D3 D2 D1 D0		D7 D6 D5 D4 D3 D2 D1 D0		D7 D6 D5 D4 D3 D2 D1 D0		П
S	S Slave Address	1	Α	Data	Α	Data	Α	Data	Α	Data	Α	Р
	Slave Address	1		of Register 1		of Register 2		of Register 3		of Register 4		il

S: Start condition, A: Acknowledge, P: Stop condition

Figure 4: Format of read mode.

#### 5. Hi-Z mode

This is built in a high impedance mode of amplifier output.

When this function is operated, HP\_EN of resister 1 is set "0" and Hi-Z of resister 3 is set "1".

#### 6. SGND

This terminal is used when it is combined as an FM tuner antenna and the headphone GND. A current connection is showed in figure 5. In case of this connection, the separation characteristic becomes bad by inductor. But this IC can prevent deterioration of separation by a connection of Figure 6.

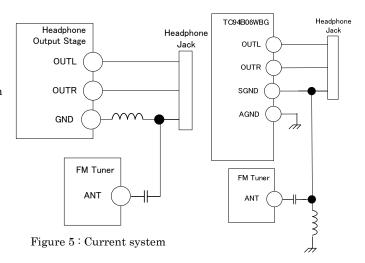


Figure 6: Connection of this IC

Timing charts may be simplified for explanatory purpose.

These protection functions are intended to avoid some output short circuits or other abnormal conditions temporarily. These protect functions do not warrant to prevent the IC from being damaged.

In case of the product would be operated with exceeded guaranteed operating ranges, these protection features may result in the IC being damaged.

The over current protection feature is only intended to protect the IC from a temporary short circuit.

Long time short circuit may stress excessively on the IC to be damaged. The system must be configured so that any over current condition will be eliminated as soon as possible.

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### **Absolute Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	AVDD	-0.3 to 5.5	V
Differential input voltage	Vin (rms)	HPVss+0.5V to HPVDD-0.5	V
I2C voltage range	VI2C	-0.3 to AVDD	V
Breakdown Voltage at amplifier outputs	Vo	5.5	V
Output protection diodes breakdown current	lo	200	mA
Power dissipation	P <sub>D</sub> (Note)	1.4	W
Operating temperature	T <sub>opr</sub>	-30 to 85	°C
Storage temperature	T <sub>stg</sub>	-55 to 85	°C

Note: Derated by 14mW/°C above Ta = 25°C

The absolute maximum ratings of a semiconductor device are a set of specified parameter values, which must not be exceeded during operation, even for an instant.

If any of these rating would be exceeded during operation, the device electrical characteristics may be irreparably altered and the reliability and lifetime of the device can no longer be guaranteed.

Moreover, these operations with exceeded ratings may cause break down, damage and/or degradation to any other equipment.

Applications using the device should be designed such that each absolute maximum rating will never be exceeded in any operating conditions.

Before using, creating and/or producing designs, refer to and comply with the precautions and conditions set forth in this documents.



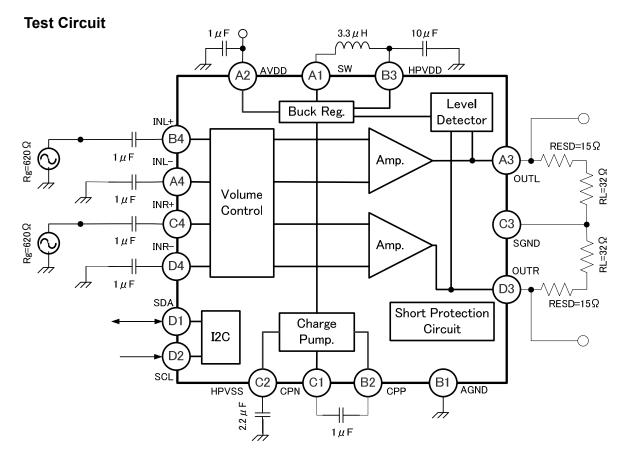
## **Electrical Characteristics**

Unless otherwise specified,

AVDD = 3.6 V, Rg = 600  $\Omega$ , RL = 15  $\Omega$ +32  $\Omega$ , f = 1 kHz, Ta = 25°C

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Shutdown Current	Isd	SW shutdown	_	_	5	μΑ
Quiescent Current	IDDQ	Both channels enabled. No audio signal	_	1.3	1.5	mA
		0.1mW*2ch, 3dB@Crest Factor	_	2.9	3.5	mA
Supply Current	Is	0.5mW*2ch, 3dB@Crest Factor	_	4.8	5.5	mA
		1mW*2ch, 3dB@Crest Factor	_	6.2	7.5	mA
	Vo1	RL=16Ω only, Gv=+4dB	0.62	0.76	_	V
Amplifier Output Voltage (rms)	VOI	THD+N=1%, L+R in phase	0.02			
	Vo2	RL=32 Ω only, Gv=+4dB	0.9	0.95	_	V
	VOZ	THD+N=1%, L+R in phase	0.9			
Total Harmonic Distortion + Noise	THD+N	Vo=500mVrms	_	0.015	0.02	%
Power Supply Rejection Ratio	PSRR	Gv=0dB, fr=217Hz(Square), 300mVrms	90	102	_	dB
Common-mode Rejection Ratio	CMRR	Gv=0dB, Vin=0.7Vrms	_	50	_	dB
Signal to Noise Ratio	S/N	f=1kHz, Vo=1Vrms, A-Weight	100	102	_	dB
Channel Separation	SEP1	RL=16Ω, Vo=0.63Vrms	60	82	_	dB
Charmer ocparation	SEP2	RL=10kΩ, Vo=0.63Vrms	80	85	_	dB
Output Noise (rms)	Vno	Gv=0, Rg=0, A-weight	_	7.5	9	μV
Output DC offset	⊿Vo	Both channels enabled, Mute on	-500	0	500	μV
Input Impedance	Zin	Differential	50	97	_	kΩ
Wake-up time	Tstart			2	3	ms
	Zout1	HiZ mode, f<40kHz	10 45	45	_	kΩ
Output Impedance	Zout2	HiZ mode, f=6MHz	500	640	—	Ω
	Zout3	HiZ mode, f=36MHz	_	135	_	Ω
Control Voltage (H)	Vih	AVDD=2.9~4.5V	1.2	_	—	V
Control Voltage (L)	Vil	AVDD=2.9~4.5V		_	0.6	V
Input Current (H)	lih	SCL/SDA, Vih=AVDD	_	_	1	μΑ
Input Current (L)	lil	SCL/SDA, Vil=0V	_	_	1	μΑ
Buck Regulator Switching Frequency	fBUCK			2		MHz
Charge pump Switching Frequency 1	fPUMP1	Po=0.1mW	_	250	_	kHz
Charge pump Switching Frequency 2	fPUMP2	Po=10mW	_	500	_	kHz
IC protection operating Current	IPRT	IC output stage current	_	150	_	mA
Common mode Voltage Range	VCM		0		1.2	V

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Inductor

Type No. MDT2520-CR3R3M (TOKO)

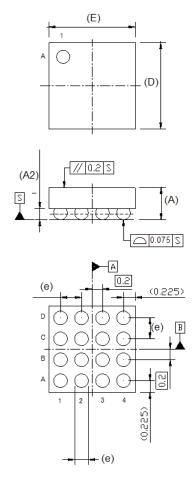
It is necessary to connect RESD to keep the oscillation margin in the application.

Components in the test circuits are only used to obtain and confirm the device characteristics. These components and circuits do not warrant to prevent the application equipment from malfunction or failure.

## **Package Dimensions**

S-UFBGA16-0202-0.40A02





Description	Min	Nom	Max	
Body size (E, mm)	1.60	1.65	1.70	
Body size (D, mm)	1.60	1.65	1.70	
Overall thickness (A, mm)	0.57	0.61	0.65	
Terminal pitch (e, mm)	-	0.40	-	
Ball / terminal diameter (b, mm)	0.23	0.26	0.29	
Body height (A1, mm)	0.39	0.41	0.44	
Ball height (A2, mm)	0.17	0.20	0.23	
Coplanarity at terminal / ball side (mm)	-	-	0.08	

- Use an appropriate power supply fuse to ensure that a large current does not continuously flow in case of over
  current and/or IC failure. The IC will fully break down when used under conditions that exceed its absolute
  maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs from the wiring or
  load, causing a large current to continuously flow and the breakdown can lead smoke or ignition. To minimize the
  effects of the flow of a large current in case of breakdown, appropriate settings, such as fuse capacity, fusing time
  and insertion circuit location, are required.
- If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the design to
  prevent device malfunction or breakdown caused by the current resulting from the inrush current at power ON or
  the negative current resulting from the back electromotive force at power OFF. For details on how to connect a
  protection circuit such as a current limiting resistor or back electromotive force adsorption diode, refer to individual
  IC datasheets or the IC databook. IC breakdown may cause injury, smoke or ignition.
- Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause injury, smoke or ignition.
- Carefully select external components (such as inputs and negative feedback capacitors) and load components (such as speakers), for example, power amp and regulator. If there is a large amount of leakage current such as input or negative feedback condenser, the IC output DC voltage will increase. If this output voltage is connected to a speaker with low input withstand voltage, overcurrent or IC failure can cause smoke or ignition. (The over current can cause smoke or ignition from the IC itself.) In particular, please pay attention when using a Bridge Tied Load (BTL) connection type IC that inputs output DC voltage to a speaker directly.
- Over current Protection Circuit
   Over current protection circuits (referred to as current limiter circuits) do not necessarily protect ICs under all circumstances. If the Over current protection circuits operate against the over current, clear the over current status immediately. Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the over current protection circuit to not operate properly or IC breakdown before operation. In addition, depending on the method of use and usage conditions, if over current continues to flow for a long time after operation, the IC may generate heat resulting in breakdown.

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